

XA-9612
PATENT APPLICATION

JC903
U.S. PTO
10/046077
01/16/02

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the application of:

Hiroshi INAGAWA et al.

Appln. No.:

Filed: Herewith

For: INSULATED GATE TYPE SEMICONDUCTOR DEVICE AND METHOD FOR
FABRICATING THE SAME

* * *

INFORMATION DISCLOSURE STATEMENT

Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

Pursuant to 37 C.F.R. § 1.56, and without any assertion
as to materiality or prior art effect, the documents listed
on the attached Form PTO-1449 are hereby cited.

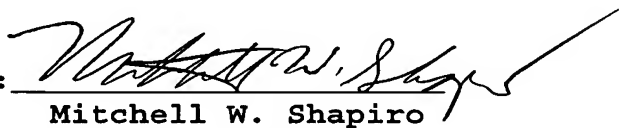
The documents on the attached List are cited in the
specification, on pages 1 and 3, and their relevance is
indicated therein.

Respectfully submitted,

MWS:jab

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By:


Mitchell W. Shapiro
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January 16, 2002